

Edge State Crossing in a Multi-Band Tight-Binding Model of Graphene

Thorben Schmirander, Daniela Pfannkuche and Marta Prada

MOTIVATION

- Graphene nanoribbons terminated by zigzag edges: **Topological insulators**
- Intrinsic spin-orbit coupling: **Conducting helical edge states** at sample boundaries cross the Brillouin zone between Dirac points $[1,2]$
- **Multi-orbital tight-binding model** with p_{z-} , d_{xz-} and d_{yz-} orbitals
- Coulomb interactions change dispersion of edge states, treated in tight-binding model by **effective mean-field**
- **Three different magnetic phases** of edge states with different topological properties
- **ground state of nanoribbons** with different sizes, energies of edge magnetic phases for **different interaction strengths**
- Coulomb interactions in **higher-energy d-orbitals** is analyzed and compared to single-orbital model

MULTI-BAND TIGHT-BINDING MODEL OF GRAPHENE

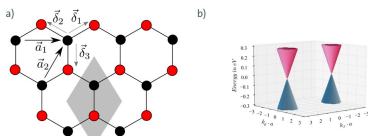


Fig. 1: a) The honeycomb lattice of graphene with lattices A and B. The lattice vectors are \vec{a}_1 and \vec{a}_2 , the vectors \vec{c}_1 , \vec{c}_2 , and \vec{c}_3 point to the nearest neighbors. The primitive unit cell is shaded gray. b) The two non-equivalent Dirac cones in graphene.

- Effective **low-energy Hamiltonian** with the sublattice spin $\hat{\sigma}$ and the valley isospin $\hat{\tau}_z$ (Fig. 1a + 1b)

$$H_0 = -v_F \hbar (\hat{\tau}_z \hat{\sigma}_x k_x + \hat{\sigma}_y k_y)$$

- Multi-orbital tight-binding model is defined via

$$H_K = \sum_{\mu\nu} E_{\mu\nu} \delta_{\mu\nu} (\hat{\alpha}_K^\mu \hat{\alpha}_K^\nu + \hat{\beta}_K^\mu \hat{\beta}_K^\nu) + \sum_{\mu\nu} e^{-i\vec{k}\cdot\vec{r}_{\mu\nu}} (\hat{\alpha}_K^\mu / \hat{\alpha}_K^\nu) \hat{\alpha}_K^\mu \hat{\beta}_K^\nu + \text{h.c.}$$

- Included: Real spin + orbitals $\mu, \nu \in \{p_z, d_{xz}, d_{yz}\}$
- Ladder operators for the A and B sublattices $\hat{\alpha}_K$ and $\hat{\beta}_K$
- Periodic in one direction and terminated by **zigzag edges** in the other (Fig. 2a)
- Edge states: **peak in density of states** (Fig. 2b)
- dispersion of edge states in the single-orbital model is flat (Fig. 2c, left)
- d-orbitals break electron-hole symmetry (Fig. 2c, right)
- **Slater-Koster approximation** is used for hopping matrix elements (Fig. 2d)

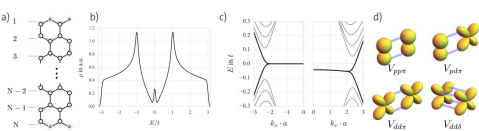


Fig. 2: a) The unit cell is comprised of N rows and 4 columns is terminated by zigzag edges. Two edge states at $k_x = 0$ are depicted in red and blue. b) The edge states result in a pronounced peak in the density of states. c) The dispersion relation of the edge states (bold) of the single-orbital model (left) and of the multi-orbital tight binding model (right). d) The differential material parameters used in the Slater-Koster approximation [2].

ELECTRONIC INTERACTIONS IN A MULTI-ORBITAL TIGHT-BINDING MODEL

- Matrix elements p_{z-} orbitals by index p and those for the d-orbitals by index $n \in \{1, \dots, 5\}$
 - **On-site interaction Hamiltonian** in multi-orbital tight-binding model:
- $$H_{pd}^{ee} = U_p \hat{n}_{p\uparrow} \hat{n}_{p\downarrow} + \sum_n (V_n (\hat{n}_{p\uparrow} \hat{n}_{n1} + \hat{n}_{p\downarrow} \hat{n}_{n\uparrow}) + J_n (\hat{c}_{p\uparrow}^\dagger \hat{c}_{n1}^\dagger \hat{c}_{n\uparrow} \hat{c}_{p\uparrow} + \hat{c}_{p\downarrow}^\dagger \hat{c}_{n1}^\dagger \hat{c}_{n\downarrow} \hat{c}_{p\downarrow} + \text{h.c.})) + (V_n - J_n) (\hat{n}_{p\uparrow} \hat{n}_{n\uparrow} + \hat{n}_{p\downarrow} \hat{n}_{n\downarrow})$$
- First term: **Single-orbital Hubbard term** for p_{z-} orbitals with interaction U
 - Second: Coulomb repulsion of electrons in **different orbitals, with different spins**
 - Third: Non-classical **exchange**
 - Forth: Coulomb repulsion of electrons in **different orbitals with same spin**
 - interaction matrix elements for d-orbitals are considered the same: $V := V_n$ and $J := J_n$
 - **only two d-orbitals** couple to p-orbitals by symmetry (n=2)
 - **mean-field approximation:**
- $$\hat{n}_{\uparrow} \hat{n}_{\downarrow} = ((\hat{n}_{\uparrow} + \Delta \hat{n}_{\uparrow}) (\hat{n}_{\downarrow} + \Delta \hat{n}_{\downarrow}) - \Delta \hat{n}_{\uparrow} \Delta \hat{n}_{\downarrow}) \approx -(\hat{n}_{\uparrow}) (\hat{n}_{\downarrow}) + \hat{n}_{\uparrow} (\Delta \hat{n}_{\downarrow}) + \hat{n}_{\downarrow} (\Delta \hat{n}_{\uparrow})$$

THE HARTREE-FOCK METHOD AND BREAKING SYMMETRIES

- Hartree-Fock method approximates **electronic interactions via a self-consistent field** [4]
- **different symmetries must be broken** in the initial matrix elements before the first computation, for reaching specific types of solutions
- **ferromagnetic edge phase (FM): time-reversal symmetry (TR)** must be broken, which is achieved by a half-filled system with a spin imbalance
- **antiferromagnetic edge phase (AFM): spin-spatial symmetry** must be broken, such that the edges exhibit opposing spin polarization with respect to each other at half-filling
- **non-magnetic edge phase: electron-hole symmetry (EH)** must be broken and a doped solution is computed. Possibly by changing the chemical potential of the system with an offset from half-filling.

NON-MAGNETIC EDGE PHASE

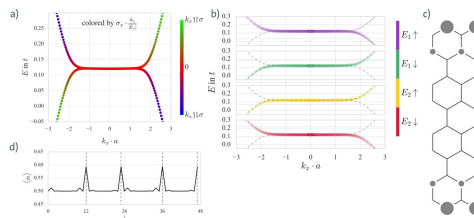


Fig. 3: a) Dispersion relation of the edge states in the non-magnetic edge phase. The model has 12x4 sites and only a single-band. b) The four individual energy bands colored by sublattice spin and real spin expectation values. c) The occupation of two edge states located at opposing edges. Occupation has contributions from both spin up and down in equal amounts. d) Particle number expectation value per site. The four sites of the edges are marked by dashed vertical lines.

- **Non-magnetic edge phase similar to non-interacting system** (Fig. 3a, 3c)
- Four states **cross band gap** according to their edge helicity: **alignment of sublattice and real spin** (Fig. 3b)
- **Density accumulates** at only one sublattice at each edge (Fig. 3c, 3d)
- can only be **obtained with doping**: **changes energy of the phase** compared to half-filling
- energy difference between a solution at doping obtained with self-consistency and at half filling (Fig. 4a, 4b)

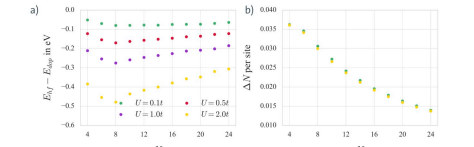


Fig. 4: a) Energy difference between nonmagnetic phase at doped self-consistent solution and same solution computed at half filling for ribbons of size Nx4 sites. Single band-model for different U. b) Particle number difference of doped solution from half filling as in a).

FERROMAGNETIC EDGE PHASE

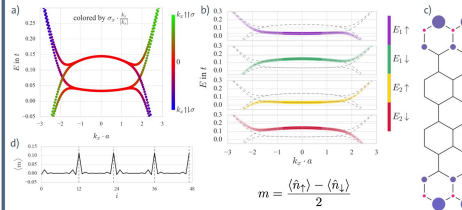


Fig. 5: a) The dispersion relation of a 12x4 size nanoribbon in the FM edge phase, colored by the bulk chirality. b) The four edge energies in the FM phase colored by the sublattice and real spin expectation values. The other three states are indicated by dashed lines. c) A schematic of the spin distribution of the system for the half-filled system. d) The magnetization expectation value resolved per site. The four edge sites are indicated by vertical dashed lines.

- **FM phase: Two spin-up states are lower in energy**, indicated by energy gap of the two states at each edge (Fig. 5a, 5b)
- **Occupy different sublattices** (Fig. 5c). Edge atoms exhibit parallel spin polarization on one sublattice, other sublattice is polarized in opposing direction: **local ferromagnetic structure**
- **Both edges have parallel spin alignment** with respect to each other (Fig. 5d)

ANTI-FERROMAGNETIC EDGE PHASE

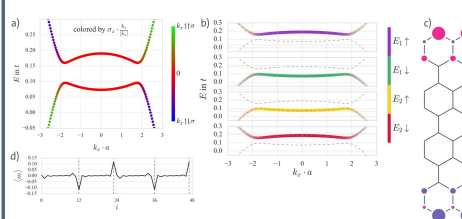


Fig. 6: a) Dispersion relation of 12x4 size nanoribbon in AFM edge phase. b) Four edge state energies of the AFM phase colored by sublattice and real spin expectation values. Other states are indicated by dashed lines. c) Schematic of spin types occupying each site of the nanoribbon at half-filling. d) The magnetization expectation value resolved per site. The four edge sites are indicated by vertical dashed lines.

- **AFM phase: Band structure exhibits a gap** (Fig. 6a)
- Two states with **anti-parallel sublattice and real spin** are lower in energy compared to parallel alignment (Fig. 6b)
- At each edge: **local ferromagnetic structure**
- both edges have **anti-parallel spin alignment** (Fig. 6c, 6c)

PHASE TRANSITIONS IN A SINGLE-ORBITAL MODEL

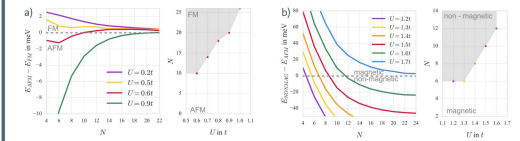


Fig. 7: a) Energy differences between the two magnetic phases for nanoribbons of different sizes for different U (left). The points of transition from an AFM to FM phase for different ribbon lengths N and interaction strengths U (right). b) The energy difference between the non-magnetic and AFM phase at different ribbon sizes for different U (left). The point of phase transition from a non-magnetic ground state to a magnetic ground state for ribbons of different sizes and interaction strengths (right).

- Energy difference of magnetic phases for nanoribbons of different sizes and U (Fig. 7a, left)
- Transition point: **FM phase is preferred for weak interactions and long ribbons** (Fig. 7a, right)
- **AFM edge phase: very short ribbons and strong interactions**
- **Non-magnetic ground state: weak interactions** (Fig. 7b, left and right)

SIZE-DEPENDENCE OF MAGNETIC PHASES

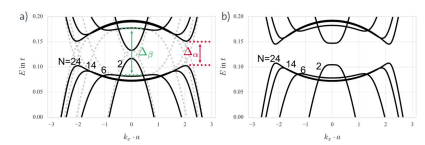


Fig. 8: a) The dispersion relations of the FM edge phase for nanoribbons of different sizes, as indicated by the numbers. The energy difference of the states at the Γ -point is defined as $\Delta_{\uparrow\downarrow}$ and at the minimum of the non-crossing states as $\Delta_{\downarrow\uparrow}$. In the FM phase this is no true gap, but defined for comparison. The dashed lines indicate these states crossing the band gap. b) The dispersion relation of the AFM phase for nanoribbons of different sizes, as indicated by the numbers.

- Dispersion relation of the FM phase (Fig. 8 a), and AFM phase (Fig. 8 b) change with number of rows N
- Two types of gaps: can be related to Coulomb interaction strength (Fig. 9)

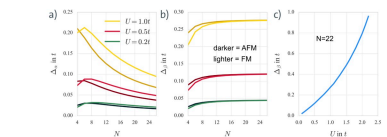


Fig. 9: a) The gap Δ_+ , as defined in Fig. 8, for different interaction strengths and different ribbon lengths. b) The gap Δ_- for different ribbon sizes. c) The gap Δ_+ and the larger than that of the AFM phase. d) As sufficiently large ribbons, such as N=22, the gap Δ_+ depends only on the interaction parameter U.

- Δ_+ marks **band gap of AFM phase** and for non-crossing states in FM phase (Fig. 9 a) for comparison
- **Increases with U**, larger for FM phase with nearly constant offset from AFM phase
- **Decreases for longer nanoribbons**
- **Gap Δ_+ converges to constant value** as length increases (Fig. 9 b), only depends on U (Fig. 9 c)

PHASE TRANSITIONS IN A MULTI-ORBITAL MODEL

INFLUENCE OF D-ORBITALS

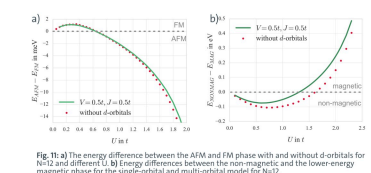


Fig. 11: a) The energy difference between the AFM and FM phase with and without d-orbitals for N=12 and different U. b) Energy differences between the non-magnetic and the lower energy magnetic phase for the single-orbital and multi-orbital model for N=12.

- Inclusion of **orbitals in multi-band tight-binding model** changes dispersion relation of edge states and energy of the phases
- Low DOS at Fermi level: **magnetic phases are nearly unaffected** (Fig. 11a)
- Peak in DOS (Fig. 2b): **Energy of non-magnetic phase changes due to d-orbitals** (Fig. 11b)

INTERACTIONS IN D-ORBITALS

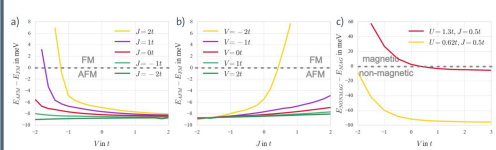


Fig. 12: a) The energy difference between the two magnetic edge phases in dependence of V for different J and U=1.61 and N=12. b) The energy difference between the two magnetic edge phases in dependence of V for different V and U=1.61 and N=12. c) Energy difference between the non-magnetic and the lower energy magnetic phase in dependence of V for two different U and N=12.

- @ $U = 1.61$: **Ground state is the AFM phase** (Fig. 11a, 11b)
- **Large attractive V**: Ground state can be **FM phase** (Fig. 12a, 12b)
- **Attractive V: Change non-magnetic ground state @ $U=1.3t$ to magnetic** (Fig. 12c)

SUMMARY

- Electronic interactions implemented via **mean-field method** in multi-band tight-binding model
- three magnetic edge phases identified and characterized
- **Non-magnetic phase is topological insulator**, exists in the case of **doping**, features density at zigzag edges and is ground state for weak Coulomb interaction strengths
- increased U: Ground state becomes **topologically trivial AFM edge phase**
- Including d-orbitals: **Energy of non-magnetic phase is increased**, due to large DOS at the Fermi energy
- **large attractive V**: Affect ground state of the system, because **occupation of d-orbitals is increased**
- Then: **Magnetic ground state at $U = 1.6t$ may become FM**, difference to single-orbital model.
- Energy of **non-magnetic edge phase** influenced by **attractive interaction**: At smaller U edge magnetic phase may become ground state

CONTACT PERSON

Thorben Schmirander
I. Institute for Theoretical Physics
University of Hamburg, Germany
Jungiusstraße 9, 20355 Hamburg

REFERENCES

- [1]: Castro Neto et al. Rev. Mod. Phys. **81**, 109 (2009)
- [2]: Kane and Mele, Phys. Rev. Lett. **95**, 146802 (2005)
- [3]: Slater and Koster, Phys. Rev. **94**, 1498 (1954)
- [4]: Claveau et al. Eur. J. Phys. **35** 035023 (2014)

Thorben.schmirander@physik.uni-hamburg.de